

Product Family Data Sheet

LH094A - AC LED









Introduction

Features

- Plastic Molded Lead Frame Type : 12.4mm(L),11.4mm(W), 4.38mm(T)
- · SMD Type : 1 Heat Pad and 4 Electrical Pad
- View Angle(△θ) * :136°
- · High Power / Brightness Chip & Long Time Reliability

Applications

- · Indoor & Outdoor lighting
- Direct AC power source plug-in (100~120Vac, 220~240Vac)

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1. Product Outline

1) Features

- · Plastic Molded Lead Frame Type: 12.4mm(L), 11.4mm(W), 4.38mm(T)
- · SMD Type: 1 Heat Pad and 4 Electrical Pad
- Beam View Angle(△θ) * :136°
- · High Power / Brightness Chip & Long Time Reliability

2) Applications

- · Indoor & Outdoor lighting
- Direct AC power source plug-in (100~120Vac, 220~240Vac)
- Wiew Angle describes the spatial intensity distribution and is the difference between the angles corresponding to 50% of the maximum intensity. (Full Width Half Maximum)

2. Absolute Maximum Rating

Parameter	Value	Unit
RMS current*	29**(240Vac) / 58**(120Vac)	mA
Power Dissipation***	4.5	W
LED Junction Temperature (T _J)	125	Ĉ
Operating Temperature Range (T _{OPR})	-40 ~ 85	Ĉ
Storage Temperature (T _{STG})	-40 ~ 120	Ĉ
ESD Sensitivity	± 3,000V HBM	-

^{*}RMS (Root mean square) current indicates AC operation at 50~60Hz

^{**} Maximum current that can be fed into LEDs depends on their configuration. Refer to p.12 and p.20

^{***} Average power dissipation only by the LED in AC operation. Power dissipation by any ballast component that is connected to the LED is not included.



3. Electro-optical Characteristics ($T_a = 25 \text{ }^{\circ}\text{C}$)

	Minimum CRI	Luminous flux [lm]						
сст [к]		I _F =22mA(rm I _F =44mA(rms	s) @ 220~240Vac* s) @ 100~120Vac**	I _F =29mA(rms) @ 220~240Vac I _F =58mA(rms) @ 100~120Vac				
		Min.	Тур.	Тур.				
2700		220	280	355				
3000	80	240	290	365				
3500	00	240	290	365				
4000		260	300	375				
5000	70	280	360	460				
6500	70	250	330	460				
Power Dissipation***			4.5W					
Operating Frequency		50/60 Hz						

^{*}Max 29mA (RMS) current is allowed by 220~240Vac configuration. Refer to [Resistor Table] on p.12.

Notes:

- 1) SAMSUNG ELECTRONICS maintains a tolerance of ±3.0 on CRI measurements.
- 2) SAMSUNG ELECTRONICS maintains a tolerance of ±7% on flux measurements.

^{**}Max 58mA (RMS) current is allowed by 100~120Vac configuration. Refer to [Resistor Table] on p.12.

^{***}Average power dissipation only by the LED in AC operation. Power dissipation by any ballast component that is connected to the LED is not included.



4. Color Binning $(T_a = 25 \text{ }^{\circ}\text{C})$

Nominal CCT	Product Code	Color Rank	Chromaticity Bins
	SPHWHTHAD605S0W0U4	W0 (Whole Bin)	WB,WC,WD,WE,WF,WG,WH
2700K	SPHWHTHAD605S0WUU4	WU (Half Bin)	WB,WC,WD
	SPHWHTHAD605S0WPU4	WP (M Sub Bin)	WB
	SPHWHTHAD605S0 <u>VO</u> VZ	V0 (Whole Bin)	VB,VC,VD,VE,VF,VG,VH
3000K	SPHWHTHAD605S0 <u>VU</u> VZ	VU (Half Bin)	VB,VC,VD
	SPHWHTHAD605S0 <u>VP</u> VZ	VP (M Sub Bin)	VB
	SPHWHTHAD605S0 <u>UO</u> VZ	U0 (Whole Bin)	UB,UC,UD,UE,UF,UG,UH
3500K	SPHWHTHAD605S0 <u>UU</u> VZ	UU (Half Bin)	UB,UC,UD
	SPHWHTHAD605S0 <u>UP</u> VZ	UP (M Sub Bin)	UB
	SPHWHTHAD605S0 <u>TO</u> WZ	T0 (Whole Bin)	TB,TC,TD,TE,TF,TG,TH
4000K	SPHWHTHAD605S0 <u>TU</u> WZ	TU (Half Bin)	TB,TC,TD
	SPHWHTHAD605S0 <u>TP</u> WZ	TP (M Sub Bin)	ТВ
5000K	SPHWHTHAD603S0R0MZ	R0 (Whole Bin)	R1,R2,R3,R4,R5,R6,R7,R8
JOOOK	SPHWHTHAD603S0RTMZ	RT (M Sub Bin)	R1,R2,R3,R4
6500K	SPHWHTHAD603S0 <u>P0</u> LZ	P0 (Whole Bin)	P1,P2,P3,P4,P5,P6,P7,P8
OSOUR	SPHWHTHAD603S0PTMZ	PT (M Sub Bin)	P1,P2,P3,P4



5. Chromaticity region & Coordinates ($T_a = 25 \text{ }^{\circ}\text{C}$)

< CIE 1931 Chromaticity diagram >

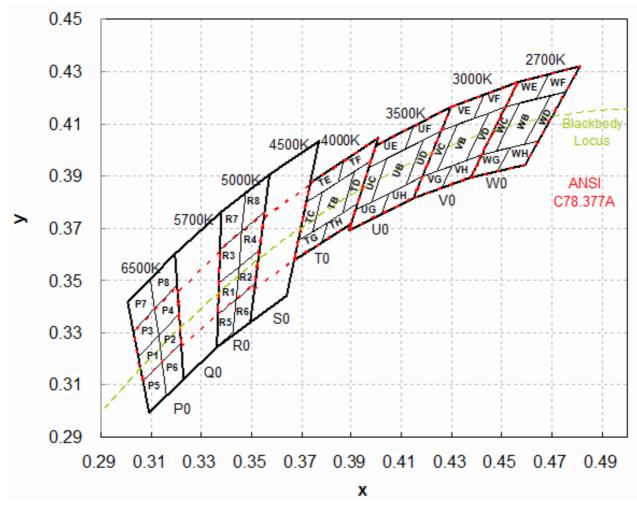


TABLE	Rank	CIE X	CIE Y	Rank	CIE X	CIE Y
		0.4697	0.4211		0.4813	0.4319
	WB	0.4576	0.4183	WF	0.4688	0.4290
	***	0.4477	0.3998	**1	0.4636	0.4196
		0.4591	0.4024		0.4758	0.4225
		0.4576	0.4183		0.4534	0.4012
	wc	0.4515	0.4168	WG	0.4420	0.3985
		0.4420	0.3985	WG	0.4373	0.3893
2700K		0.4477	0.3998		0.4483	0.3919
27001	WD	0.4758	0.4225	WH	0.4648	0.4038
		0.4697	0.4211		0.4534	0.4012
	VVD	0.4591	0.4024	VVII	0.4483	0.3919
		0.4648	0.4038		0.4593	0.3944
		0.4688	0.4290		0.4813	0.4319
	WE	0.4562	0.4260	ANSI	0.4562	0.4260
		0.4515	0.4168	ANSI	0.4373	0.3944
		0.4636	0.4196		0.4593	0.4319



TABLE	Rank	CIE X	CIE Y	Rank	CIE X	CIE Y
		0.4451	0.4146		0.4562	0.4260
	VB	0.4324	0.4100	VF	0.4431	0.4213
	VD	0.4244	0.3922	VI	0.4388	0.4122
		0.4361	0.3964		0.4515	0.4168
		0.4324	0.4100		0.4303	0.3944
	VC	0.4261	0.4077	VG	0.4185	0.3902
	VC	0.4185	0.3902	VG	0.4147	0.3814
000016		0.4244	0.3922		0.4260	0.3854
3000K	VD	0.4515	0.4168		0.4420	0.3985
		0.4451	0.4146	VH	0.4303	0.3944
		0.4361	0.3964	VII	0.4260	0.3854
		0.4420	0.3985		0.4373	0.3893
		0.4431	0.4213		0.4813	0.4319
	VE	0.4299	0.4165	ANSI	0.4562	0.4260
		0.4261	0.4077	C78.377	0.4373	0.3893
		0.4388	0.4122		0.4593	0.3944

TABLE	Rank	CIE X	CIE Y	Rank	CIE X	CIE Y
		0.4188	0.4042		0.4299	0.4165
	UB	0.4042	0.3970	UF	0.4148	0.4090
	OB	0.3983	0.3803	OI	0.4115	0.4005
		0.4118	0.3869		0.4261	0.4077
		0.4042	0.3970		0.4050	0.3837
	UC	0.3969	0.3934	UG	0.3916	0.3771
	00	0.3916	0.3771	UG	0.3889	0.3690
3500K		0.3983	0.3803		0.4018	0.3752
3300K	UD	0.4261	0.4077		0.4185	0.3902
		0.4188	0.4042	UH	0.4050	0.3837
	OD	0.4118	0.3869	OII	0.4018	0.3752
		0.4185	0.3902		0.4147	0.3814
		0.4148	0.4090		0.4813	0.4319
	UE	0.3996	0.4015	ANSI	0.4562	0.4260
		0.3969	0.3934	C78.377	0.4373	0.3944
		0.4115	0.4005		0.4593	0.4319



TABLE	Rank	CIE X	CIE Y	Rank	CIE X	CIE Y
		0.3914	0.3922		0.4006	0.4044
	ТВ	0.3784	0.3841	TF	0.3871	0.3959
	16	0.3746	0.3688	IF	0.3849	0.3880
		0.3865	0.3761		0.3979	0.3962
		0.3784	0.3841		0.3806	0.3726
	тс	0.3720	0.3800	TG	0.3687	0.3652
	10	0.3687	0.3652	10	0.3670	0.3578
4000K		0.3746	0.3688		0.3784	0.3647
4000K	TD	0.3979	0.3962		0.3925	0.3798
		0.3914	0.3922	TH	0.3806	0.3726
	10	0.3865	0.3761	111	0.3784	0.3647
		0.3925	0.3798		0.3898	0.3716
		0.3871	0.3959		0.4813	0.4319
	TE	0.3736	0.3874	ANSI	0.4562	0.4260
	'L	0.3720	0.3800	C78.377	0.4373	0.3944
		0.3849	0.3880		0.4593	0.4319

Table	Rank	CIE X	CIE Y	Rank	CIE X	CIE Y
		0.3452	0.3558		0.3441	0.3428
	R1	0.3371	0.3493	R5	0.3366	0.3369
	IXI	0.3366	0.3369	IXO	0.3361	0.3245
		0.3441	0.3428		0.3428	0.3292
		0.3533	0.3624		0.3515	0.3487
	R2	0.3452	0.3558	R6	0.3441	0.3428
	R3	0.3441	0.3428	Κo	0.3428	0.3292
5000K		0.3515	0.3487		0.3495	0.3339
3000K		0.3464	0.3688		0.3476	0.3835
		0.3376	0.3616	R7	0.3381	0.3762
	N3	0.3371	0.3493	IX/	0.3376	0.3616
		0.3452	0.3558		0.3464	0.3688
		0.3551	0.3760		0.3571	0.3907
	R4	0.3464	0.3688	R8	0.3476	0.3835
	K4	0.3452	0.3558	1.0	0.3464	0.3688
		0.3533	0.3624		0.3551	0.3760



Table	Rank	CIE X	CIE Y	Rank	CIE X	CIE Y
		0.3131	0.3290		0.3145	0.3187
	P1	0.3048	0.3209	P5	0.3068	0.3113
	FI	0.3068	0.3113	FJ	0.3093	0.2993
		0.3145	0.3187		0.3162	0.3057
		0.3213	0.3371		0.3221	0.3261
	P2	0.3131	0.3290	P6	0.3145	0.3187
	P2	0.3145	0.3187		0.3162	0.3057
CE001/		0.3221	0.3261		0.3231	0.3120
6500K	Р3	0.3117	0.3393	P7	0.3101	0.3509
		0.3028	0.3304		0.3005	0.3415
	F3	0.3048	0.3209	Γ/	0.3028	0.3304
		0.3131	0.3290		0.3117	0.3393
		0.3205	0.3481		0.3196	0.3602
	P4	0.3117	0.3393	P8	0.3101	0.3509
		0.3131	0.3290	. 0	0.3117	0.3393
		0.3213	0.3371		0.3205	0.3481

Notes:

SAMSUNG ELECTRONICS maintains ±0.01 tolerance of CCx, CCy



6. Luminous Flux $(T_a = 25 \text{ }^{\circ}\text{C})$

Product Code		2mA	W* Operation (rms) @ 220Vac (rms) @ 110Vac	4.5W** Operation 29mA(rms) @ 220Vac 58mA(rms) @ 110Vac	ССТ
	Rank		Flux range [lm]	Flux range [lm]	
		U1	220 ~ 240	275 ~ 300	
SPHWHTHAD605S0W0 <u>U4</u>	U4	V1	240 ~ 260	300 ~ 330	27001/
SPHWHTHAD605S0WU <u>U4</u> SPHWHTHAD605S0WPU4	04	W1	260 ~ 280	330 ~ 355	2700K
31 11W1111AD00330W1 <u>04</u>		X1	280~	355~	
		V1	240 ~ 260	285 ~ 310	
SPHWHTHAD605S0V0VZ	VZ	W1	260~ 280	310 ~ 340	3000K
SPHWHTHAD605S0VU <u>VZ</u> SPHWHTHAD605S0VPVZ	VZ	X1	280 ~ 300	340 ~ 365	3000K
<u> </u>		01	300 ~	365 ~	
		V1	240 ~ 260	285 ~ 310	
SPHWHTHAD605S0U0VZ	\/7	W1	260 ~ 280	310 ~ 340	3500K
SPHWHTHAD605S0UU <u>VZ</u> SPHWHTHAD605S0UPVZ	VZ	X1	280 ~ 300	340 ~ 365	
SPIIWIIIIAD003300F VZ		01	300 ~	365 ~	
		W1	260 ~ 280	290 ~ 320	
SPHWHTHAD605S0V0WZ	WZ	X1	280 ~ 300	320 ~ 350	4000K
SPHWHTHAD605S0VUWZ SPHWHTHAD605S0VPWZ	VVZ	01	300 ~ 320	350 ~ 370	4000K
<u> </u>		11	320 ~	370 ~	
		M1	280 ~ 310	355 ~ 395	
SPHWHTHAD603S0R0MZ	MZ	N1	310 ~ 340	395 ~ 435	5000K
SPHWHTHAD603S0RTMZ	IVIZ	P1	340 ~ 370	435 ~ 470	30001
		Q1	370 ~	470 ~	
		L1	250 ~ 280	315 ~ 355	
SPHWHTHAD603S0P0LZ	LZ	M1	280 ~ 310	355 ~ 395	6500K
SPHWHTHAD603S0PTLZ		N1	310 ~ 340	395 ~ 435	300010
		P1	340 ~	435 ~	

^{*} Reference binning is done at I_F =22mA(rms), 3.3W.

*.8)

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^{**} Luminous flux at 4.5W operation is calculated by extrapolation form measured luminous flux at 3.3W operation.



7. Vf Binning $(T_a = 25 \degree)$

Symbol	Condition	Rank		Min.	Тур.	Max.	Unit	
	Vf* $I_F = 22\text{mA}(\text{rms})$			F1	185	-	195	
Vf*		S0	F3	195	-	200	Vac (rms)	
			F5	200	-	205	()	

^{*} Tolerance : ±5V

^{*} The LED is directly connected to a test source without any additional components, when measured. The test source imposes sinusoidal current waves at 60Hz (22mA rms) across the LED, and Vf is measured in RMS.



8. Resistor Table ($T_a = 25 \text{ }^{\circ}\text{C}$)

Vin	Vf Bin	Target PKG Power Dissipation*			
(RMS)	VI DIII	3.3W @ I _F =44mA	4.0W @ I _F =53mA	4.5W @ <i>I_F</i> =58mA	
	F1	330 Ω	240 Ω	200 Ω	
100Vac	F3	300 Ω	230 Ω	190 Ω	
	F5	270 Ω	220 Ω	180 Ω	
	F1	560 Ω	430 Ω	360 Ω	
110Vac	F3	510 Ω	410 Ω	360 Ω	
	F5	460 Ω	390 Ω	360 Ω	
	F1	800 Ω	620 Ω	560 Ω	
120Vac	F3	750 Ω	620 Ω	545 Ω	
	F5	700 Ω	620 Ω	530 Ω	

Vin	Vf Bin	Target PKG Power Dissipation*				
(RMS)	VI DIII	3.3W @ <i>I_F</i> =22mA	4.0W @ I _F =26.5mA	4.5W @ <i>I_F</i> =29mA		
	F1	2.3 K Ω	1.7 K Ω	1.5 K Ω		
220Vac	F3	2.1 K Ω	1.65 Κ Ω	1.46 K Ω		
	F5	1.9 K Ω	1.6 K Ω	1.43 K Ω		
	F1	2.62 Κ Ω	2.1 K Ω	1.9 K Ω		
230Vac	F3	2.56 K Ω	2.05 K Ω	1.85 K Ω		
	F5	2.5 KΩ	2.0 KΩ	1.8 K Ω		
	F1	3.1 KΩ	2.5 K Ω	2.2 K Ω		
240Vac	F3	3.0 KΩ	2.5 K Ω	2.2 K Ω		
	F5	2.9 K Ω	2.5 K Ω	1.2 K Ω		

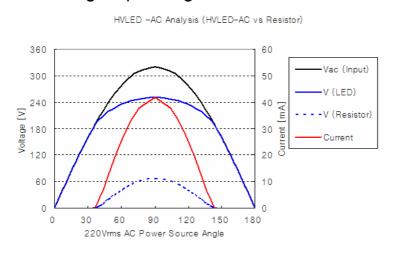
HV-AC LED can be wired in two types of configuration: one is serial connection to be applicable to the mains of 220~240Vac, and the other is parallel connection to the mains of 100~120Vac. Each configuration is wired by foot print pattern, on which the LED is mounted. For the recommended foot print design, see "8.circuit design section" on p.21.

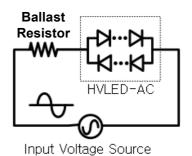
^{*} Proper selection of resistor values should be made for LEDs to be driven at the desired current level with acceptable tolerance specified above. The table above summarizes recommended resistor values for the mains voltages by country, and the LED's Vf bin.



9. Typical Characteristic Graphs

1) AC voltage operating characteristic

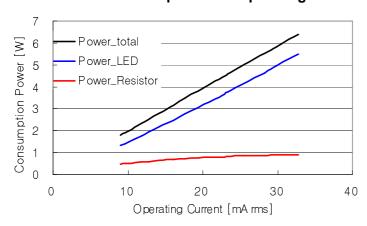




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Total Power Consumption = Power_LED + Power_Resistor Power_LED = Total Power - I^2R

< Power consumption vs. Operating current >



< LED Input Power vs. Generated Heat >



※ Total Thermal dissipation = LED + Resistor

Thermal dissipation of the LED is the vertical axis of the above graph.

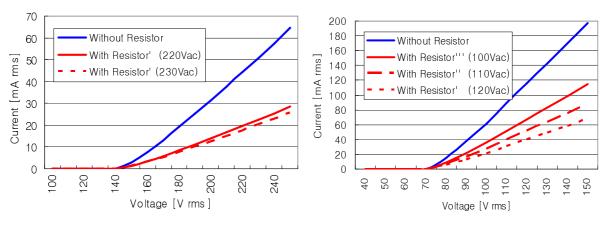
Thermal dissipation of the resistor is Current² X Resistance.

Proper resistor value and type must be selected depending on the operating condition.

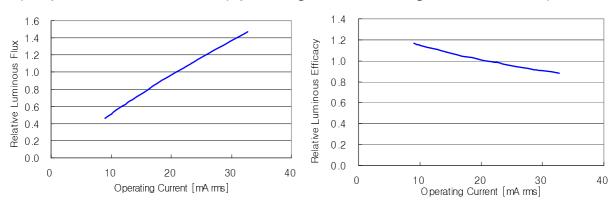
Http://www.samsungled.com



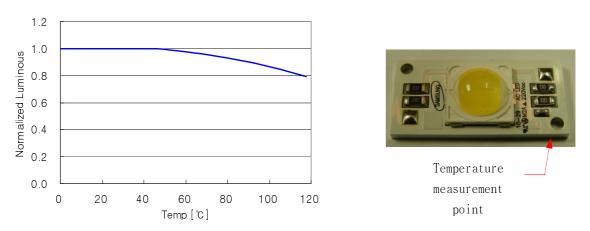
2) IV characteristic (operating in AC voltage, T_a = 25 °C)



3) Optical characteristic (operating in AC voltage, T_a = 25 °C)



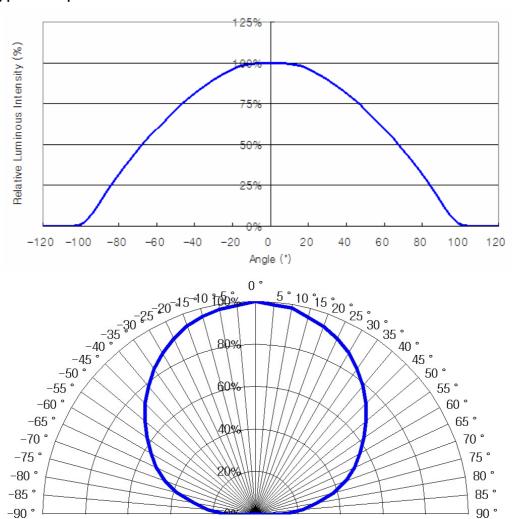
4) Thermal characteristic (operating in AC voltage, Ta = 25 °C)



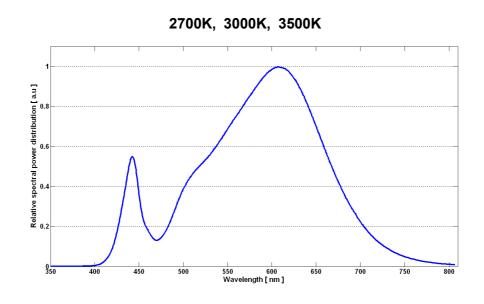
*Temperature is measured on bottom surface of metal PCB with ballast resistors mounted.



5) Typical Spatial Distribution

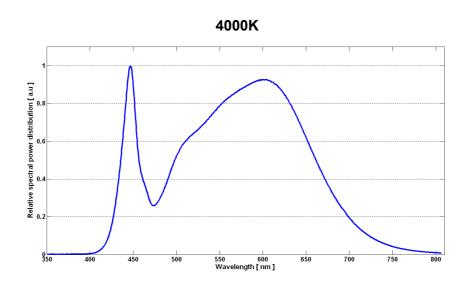


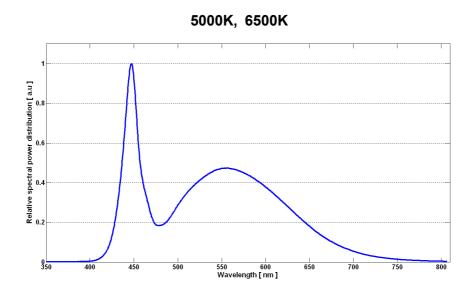
6) Spectrum Distribution



Http://www.samsungled.com

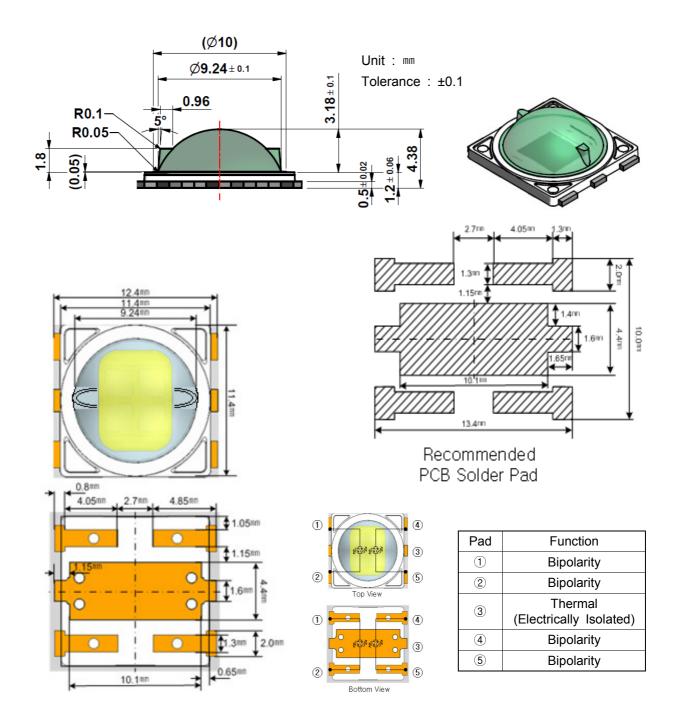








10. Outline Drawing and Pad Configuration



Pick and Place

- 1. Do not place pressure on the encapsulating resin

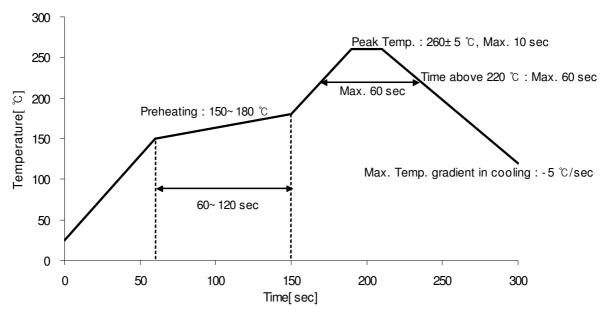
 It is recommended to use a pick&place nozzle with inside diameter at 9.2mm
- 2. The maximum compressing force is 20N on the polymer

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11. Solder Conditions

1) Reflow Conditions (Pb-Free) Reflow Frequency: 2 time max.



2) For Manual Soldering

Not more than 5 seconds @Max. 300 °C, under soldering iron.



12. Reliability Test Items and Conditions

1) Test Items

Test Items	Test Conditions	Test Hours/Cyc les
Room Temperature life test	25℃, IF = Max AC 25mA(rms)	1,000 h
High Temperature humidity life test	85℃, 85% RH, IF = Max AC 25mA(rms)	1,000 h
High Temperature life test	85℃, IF = Max AC 25mA(rms)	1,000 h
Low Temperature life test	-40℃, IF = Max AC25mA(rms)	1,000 h
High Temperature Storage	120℃	1,000 h
Low Temperature Storage	-40℃	1,000 h
Thermal Shock	-40 / 120℃, each 30 min	200 cycles
Temperature humidity Cycle On/Off test	-40 / 85℃, each 20 min, 100 min transfer Power On/off each 5 min, AC 20 mA	100 cycles
Reflow (Pb-Free)	Peak 260±5℃ for 10 sec	3 times
ESD(HBM)	R1 : 10 M Ω , R2 : 1.5 k Ω , C : 100 pF	5 times (± 2 kV)
Surge	Line to Line	2 kV

2) Criteria for Failure

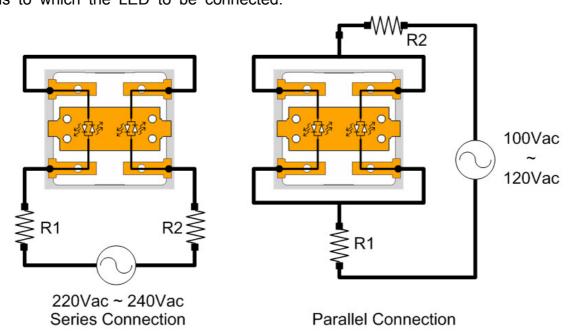
Item	Symbol	Test Condition	Limit		
Itom	Cymbol	rest condition	Min	Max	
Forward Voltage	V _F	$I_F = 22 \text{ mA}(\text{rms})$	-	U.S.L.*1.2	
Luminous Flux	Фу	$I_F = 22 \text{ mA(rms)}$	L.S.L.*0.7	-	

* U.S.L : Upper Standard Level, L.S.L : Lower Standard Level

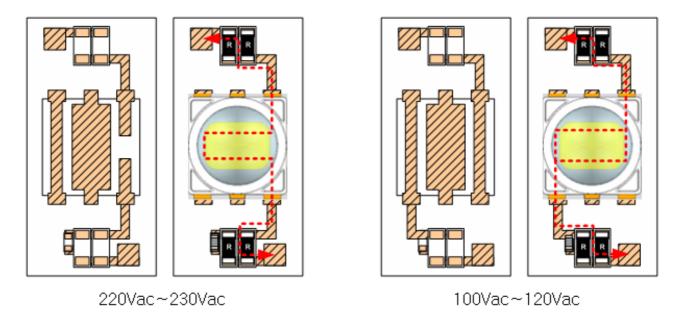


13. Circuit Design - Package and PCB

As illustrated below, two different configurations are possible depending on electric mains to which the LED to be connected.



Schematic Circuit Connection (Example)



PCB Pattern Circuit (Example)

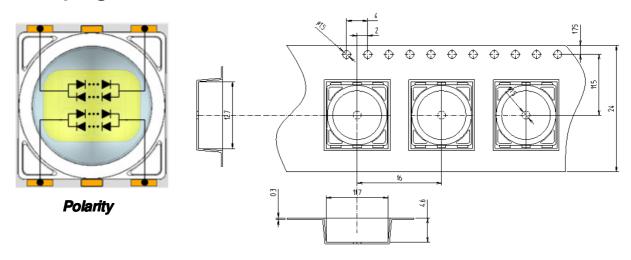
To improve protection against surge, two pairs of identical resistors connected in parallel are symmetrically added to the LED so that total equivalent resistance, the sum of R1 and R2, is equal to the value on p.12.

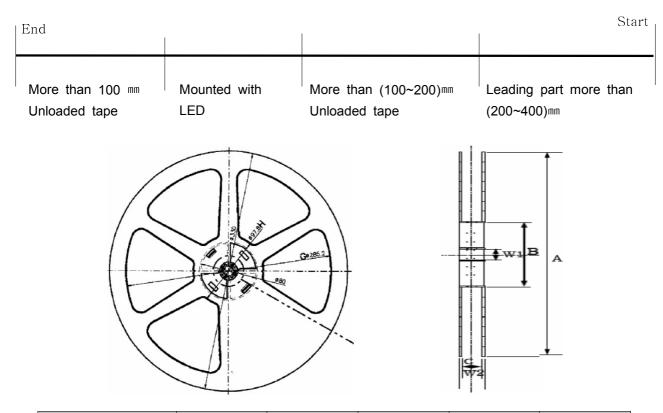
Http://www.samsungled.com

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14. Taping Dimension





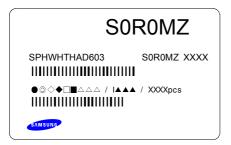
Symbol	Α	В	С	W1	W2	
Dimension(mm)	330 ± 1	80 ± 1	25 ± 0.5	13 ± 0.3	29.5 ± 1	

- (1) Quantity: 800 Pcs / 13" Reel.
- (2) Cumulative Tolerance: Cumulative Tolerance/10 pitches is less than ±0.2 mm
- (3) Adhesion Strength of Cover Tape: Adhesion strength to be 0.1-0.7N when the cover tape is turned off from the carrier tape at 10 °C angle to be the carrier tape.
- (4) Packaging: P/N, Manufacturing data Code No. and quantity to be indicated on a damp proof Package

21 / 31



15. Label Structure



Rank Code

/S0/ : VF Rank (refer to page 3)

/R0/ : Chromaticity Coordinate Rank, CIE (refer to page 4)

/MZ/: Luminous Flux (refer to page 4)

11. Lot Number

The Lot number is composed of the following characters

● ◎ ◇ ◆ □ ■ △ △ △ / I ▲ ▲ ▲ / 800PCS

• : Production Site (S:SAMSUNG LED, G:Gosin China)

♦ : Product State (A:Normality, B:Bulk, C:First Production, R:Reproduction, S:Sample)

♦ : Year (S:2008, T:2009, U:2010...)

☐ : Month (1 ~ 9, A, B)

■ : Day (1 ~ 9, A, B ~ V)

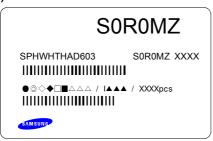
△ : SAMSUNG LED Product Number (1 ~ 999)

▲ : Reel Number (1 ~ 999)

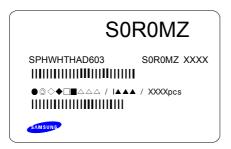


16. Reel Packing Structure

1) Reel



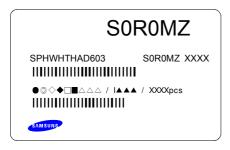
2) Aluminum Bag



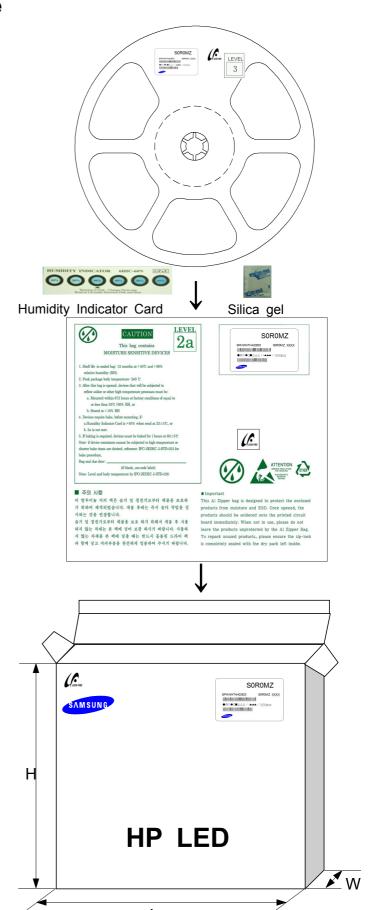
3) Inner Box

Material: Paper(SW3B(B))

TYPE	SIZE(mm)				
IIPE	L	W	Н		
13inch	335	45	335		



*.8)



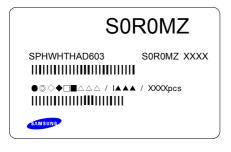
Http://www.samsungled.com

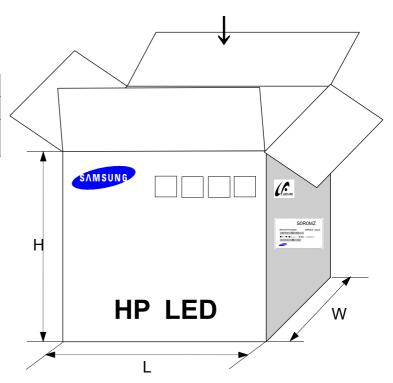


4) Carton Box

Material: Paper(SW3B(B))

TYPE	SIZE(mm)			
IIFL	L	W	Н	
13inch	350	350	350	







17. Aluminum Packing Bag



CAUTION

2a

This bag contains MOISTURE SENSITIVE DEVICES

- 1. Shelf life in sealed bag: 12 months at $< 40^{\circ}$ C and < 90% relative humidity (RH)
- 2. Peak package body temperature: 240 $^{\circ}\mathrm{C}$
- 3. After this bag is opened, devices that will be subjected to reflow soldor or other high temperature processes must be:

 - b. Stored at < 10% RH
- Devices require bake, before mounting, if:
 a.Humidity Indicator Card is > 65% when read at 23±5°C, or
 b. 2a is not met.
- 5. If baking is required, devices must be baked for 1 hours at 60±5°C Note: if device containers cannot be subjected to high temperature or shorter bake times are desired, reference IPC/JEDEC J-STD-033 for bake procedure,

Bag seal due date:

(if blank, see code label)

Note: Level and body temperature by IPC/JEDEC J-STD-020







S0R0MZ

SOROMZ XXXX

SPHWHTHAD603

SAMSUNG

●◎◇◆□■△△△ / I▲▲▲ / XXXpcs



■ 주의 사항

이 알루미늄 지퍼 백은 습기 및 정전기로부터 제품을 보호하기 위하여 제작되었습니다. 개봉 후에는 즉시 솔더 작업을 실시하는 것을 권장합니다.

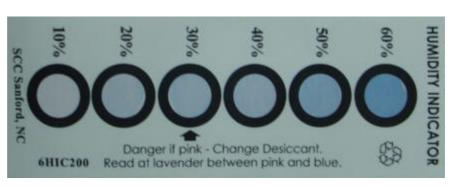
습기 및 정전기로부터 제품을 보호 하기 위해서 개봉 후 사용하지 않는 자재는 본 팩에 넣어 보관 하시기 바랍니다. 사용하지 않는 자재를 본 팩에 넣을 때는 반드시 동봉된 드라이 팩과 함께 넣고 지퍼부분을 완전하게 밀봉하여 주시기 바랍니다.

■ Important

This Al Zipper bag is designed to protect the enclosed products from moisture and ESD. Once opened, the products should be soldered onto the printed circuit board immediately. When not in use, please do not leave the products unprotected by the Al Zipper Bag. To repack unused products., please ensure the zip-lock is completely sealed with the dry pack left inside.

Silica gel & Humidity Indicator Card in Aluminum Packing Bag





Http://www.samsungled.com

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18. Precaution for Use

- For over-current-proof function, customers are recommended to apply resistors to prevent sudden change of the current caused by slight shift of the voltage.
- 2) This device should not be used in any type of fluid such as water, oil, organic solvent, etc. When washing is required, IPA is recommended to use.
- 3) When the LEDs illuminate, operating current should be decided after considering the ambient maximum temperature.
- 4) LEDs must be stored in a clean environment. If the LEDs are to be stored for 3 months or more after being shipped from SAMSUNG LED, they should be packed by a sealed container with nitrogen gas injected. (Shelf life of sealed bags : 12 months, temp. 0~40℃, 20~70%RH)
- 5) After storage bag is open, device subjected to soldering, solder reflow, or other high temperature processes must be:
 - a. Mounted within 168 hours (7days) at an assembly line with a condition of no more than $30 \, ^{\circ}\text{C}/60\%\text{RH}$,
 - b. Stored at <10% RH.
- 6) Repack unused Products with anti-moisture packing, fold to close any opening and then store in a dry place.
- 7) Devices require baking before mounting, if humidity card reading is >60% at $23\pm5\,^{\circ}$ C.
- 8) Devices must be baked for 24hours at 65±5°C, if baking is required.

- 9) The LEDs are sensitive to the static electricity and surge. It is recommended to use a wrist band or anti-electrostatic glove when handling the LEDs.
 - If voltage exceeding the absolute maximum rating is applied to LEDs, it may cause damage or even destruction to LED devices.
 - Damaged LEDs may show some unusual characteristics such as increase in leak current, lowered turn-on voltage, or abnormal lighting of LEDs at low current.



- 10) When handling LED with tweezers, the LED Should only be held by the polymer body, not by the encapsulant or LENS.
- 11) The use of appropriate nozzle for the LED recommended. For the recommended nozzle size, refer to the figure at the below. Inner diameter of nozzle $\geq \Phi 9.2 \text{mm}$
- 12) Do not stack assembled PCBs together. Since silicone is a soft material, abrasion between two PCB assembled with silicone encapsulated LED might cause catastrophic failure of the LEDs due to damage to encapsulant and wire and LED detachment.



19. Hazard Substance Analysis



Test Report No. F690501/LF-CTSAYAA11-02161

Issued Date: January 21, 2011

Page 1 of 5

SAMSUNG LED CO., LTD.

314, Maetan-dong Yeongtong-gu Suwon-city GYEONGGI-DO 443-370

Korea

The following merchandise was submitted and identified by the client as :

: AYAA11-02161 SGS File No. **Product Name** : HV_AC LED PKG

: N/A Item No./Part No.

Received Date : Jan 18, 2011

: Jan 19, 2011 **Test Period** to Jan 20, 2011

Test Performed : SGS Testing Korea tested the sample(s) selected by applicant with following results

Test Results : For further details, please refer to following page(s)

: By the applicant's specific request, the sampling and testing was performed only for the part Comments

indicated in the photo without disassembly.

SGS Testing Korea Co. Ltd.

Timothy Jeon Jinhee Kim Cindy Park

Jerry Jung/ Testing Person

Jeff Jang / Chemical Lab Mgr

F052 Version3

322, The O valley, 555-9, Hogye-dong, Dongan-gu, Anyang-si, Gyeonggi-do, Korea 431-080 f +82 (0)31 4608 000 f +82





Test Report No. F690501/LF-CTSAYAA11-02161 Issued Date: January 21, 2011 Page 2 of 5

Sample No. : AYAA11-02161.001
Sample Description : HV_AC LED PKG

Item No./Part No. : N/A

Comments : Materials are Copper, Silicone.

Heavy Metals

Test Items	Unit	Test Method	MDL	Results
Cadmium (Cd)	mg/kg	With reference to IEC 62321:2008, ICP	0.5	N.D.
Lead (Pb)	mg/kg	With reference to IEC 62321:2008, ICP	5	N.D.
Mercury (Hg)	mg/kg	With reference to IEC 62321:2008, ICP	2	N.D.
Hexavalent Chromium (Cr VI)	mg/kg	With reference to IEC 62321:2008, UV-VIS	1	N.D.

Flame Retardants-PBBs/PBDEs

Test Items	Unit	Test Method	MDL	Results
Monobromobiphenyl	mg/kg	With reference to IEC 62321:2008, GC-MS	5	N.D.
Dibromobiphenyl	mg/kg	With reference to IEC 62321:2008, GC-MS	5	N.D.
Tribromobiphenyl	mg/kg	With reference to IEC 62321:2008, GC-MS	5	N.D.
Tetrabromobiphenyl	mg/kg	With reference to IEC 62321:2008, GC-MS	5	N.D.
Pentabromobiphenyl	mg/kg	With reference to IEC 62321:2008, GC-MS	5	N.D.
Hexabromobiphenyl	mg/kg	With reference to IEC 62321:2008, GC-MS	5	N.D.
Heptabromobiphenyl	mg/kg	With reference to IEC 62321:2008, GC-MS	5	N.D.
Octabromobiphenyl	mg/kg	With reference to IEC 62321:2008, GC-MS	5	N.D.
Nonabromobiphenyl	mg/kg	With reference to IEC 62321:2008, GC-MS	5	N.D.
Decabromobiphenyl	mg/kg	With reference to IEC 62321:2008, GC-MS	5	N.D.
Monobromodiphenyl ether	mg/kg	With reference to IEC 62321:2008, GC-MS	5	N.D.
Dibromodiphenyl ether	mg/kg	With reference to IEC 62321:2008, GC-MS	5	N.D.
Tribromodiphenyl ether	mg/kg	With reference to IEC 62321:2008, GC-MS	5	N.D.
Tetrabromodiphenyl ether	mg/kg	With reference to IEC 62321:2008, GC-MS	5	N.D.
Pentabromodiphenyl ether	mg/kg	With reference to IEC 62321:2008, GC-MS	5	N.D.
Hexabromodiphenyl ether	mg/kg	With reference to IEC 62321:2008, GC-MS	5	N.D.
Heptabromodiphenyl ether	mg/kg	With reference to IEC 62321:2008, GC-MS	5	N.D.
Octabromodiphenyl ether	mg/kg	With reference to IEC 62321:2008, GC-MS	5	N.D.
Nonabromodiphenyl ether	mg/kg	With reference to IEC 62321:2008, GC-MS	5	N.D.
Decabromodiphenyl ether	mg/kg	With reference to IEC 62321:2008, GC-MS	5	N.D.

NOTE: (1) N.D. = Not detected.(<MDL)

- (2) mg/kg = ppm
- (3) MDL = Method Detection Limit
- (4) = No regulation
- (5) ** = Qualitative analysis (No Unit)
- (6) * = Boiling-water-extraction:

Negative = Absence of CrVI coating

Positive = Presence of CrVI coating; the detected concentration in boiling-water-extraction

solution is equal or greater than 0.02 mg/kg with 50 cm2 sample surface area.

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SGS Testing Korea Co.,Ltd.

322, The O valley, 555-9, Hogye-dong, Dongan-gu, Anyang-si, Gyeonggi-do, Korea 431-080 t +82 (0)31 4608 000 f +82 (0)31 4608 059 http://www.sgsiab.co.kr.www.kr.sgs.com/greenlab

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Test Report No. F690501/LF-CTSAYAA11-02161 Issued Date: January

Issued Date: January 21, 2011 Page 3 of 5

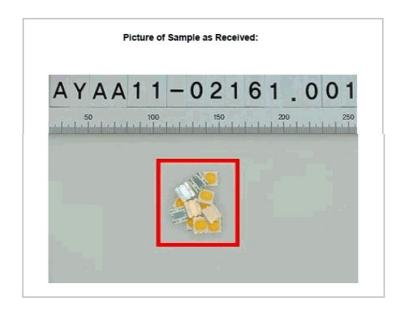
Sample No. : AYAA11-02161.001
Sample Description : HV_AC LED PKG

Item No./Part No. : N/A

Comments : Materials are Copper, Silicone.

Halogen Contents

Test Items	Unit	Test Method	MDL	Results
Bromine(Br)	mg/kg	BS EN 14582:2007, IC	30	N.D.
Chlorine(CI)	mg/kg	BS EN 14582:2007, IC	30	N.D.
Fluorine(F)	mg/kg	BS EN 14582:2007, IC	30	N.D.
lodine(I)	mg/kg	BS EN 14582:2007, IC	50	N.D.



NOTE: (1) N.D. = Not detected.(<MDL)

(2) mg/kg = ppm

(3) MDL = Method Detection Limit

(4) - = No regulation

(5) ** = Qualitative analysis (No Unit)

(6) * = Boiling-water-extraction:

Negative = Absence of CrVI coating

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Revision History (Model : HA04J)

Dete	Davisian History	Au	Author			
Date	Revision History	Drawn	Approved			
2012.10.25	Initial Edition of Product Family Data sheet	I.S. Park	M.Y. Son			
2012.10.26	Updated mechanical dimensions and details on lens shape on p.17	I.S. Park	M.Y. Son			

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